Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

1.125 inches

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

1.062 inches

Thread Size:

0.500 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

150.0 gate to substrate voltage and 180.0 reverse voltage, peak

Current Rating Per Characteristic:

50.00 amperes repetitive peak forward current

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 threaded stud and 2 insulated wire lead w/terminal lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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